

NP75N04VDK

R07DS1015EJ0200 Rev.2.00 May 24, 2018

Description

The NP75N04VDK is N-channel MOS Field Effect Transistors designed for high current switching applications.

Features

• Super low on-state resistance

 $R_{DS(on)} = 5.7 \text{ m}\Omega \text{ MAX.} (V_{GS} = 10 \text{ V}, I_D = 38 \text{ A})$

- Low C_{iss} : $C_{iss} = 1630 \text{ pF TYP}$. ($V_{DS} = 25 \text{ V}$)
- Logic level drive type
- Designed for automotive application and AEC-Q101 qualified

Ordering Information

Part No.	Lead Plating	Pac	Package	
NP75N04VDK-E1-AY *1	Pure Sn (Tin)	Tape 2500 p/reel	Taping (E1 type)	TO-252 (MP-3ZP)
NP75N04VDK-E2-AY *1			Taping (E2 type)	

Note: *1 Pb-free (This product does not contain Pb in the external electrode)

Absolute Maximum Ratings (T_A = 25°C)

Item	Symbol	Ratings	Unit	
Drain to Source Voltage (V _{GS} = 0 V)	VDSS	40	V	
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	±20	V	
Drain Current (DC) (T _c = 25°C)	ID(DC)	±75	A	
Drain Current (pulse) *1, 3	I _{D(pulse)}	±225	A	
Total Power Dissipation (T _c = 25°C)	P _{T1}	75	W	
Total Power Dissipation ($T_A = 25^{\circ}C$)	P _{T2}	1.2	W	
Channel Temperature	T _{ch}	175	°C	
Storage Temperature	T _{stg}	–55 to +175	°C	
Repetitive Avalanche Current *2, 3	I _{AR}	22	A	
Repetitive Avalanche Energy *2, 3	Ear	48	mJ	

Thermal Resistance

Channel to Case Thermal Resistance	Rth(ch-C)*3	2.00	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A) *3	125	°C/W

Notes: *1 T_C = 25°C, P_W \leq 10 $\mu s,$ Duty Cycle \leq 1%

- *2 R_G = 25 $\Omega,$ V_{GS} = 20 V \rightarrow 0 V
- *3. Not subject of production test. Verified by design/characterization.



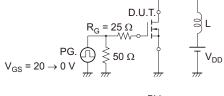
ltom	Symbol	MIN.	TYP.	MAX.	Unit	Test Conditions	
ltem	Symbol	IVIIIN.	ITP.		Unit	Test Conditions	
Zero Gate Voltage Drain Current	I _{DSS}			1	μΑ	$V_{DS} = 40 V, V_{GS} = 0 V$	
Gate Leakage Current	I _{GSS}			±100	nA	V_{GS} = ±20 V, V_{DS} = 0 V	
Gate to Source Threshold Voltage	V _{GS(th)}	1.5	1.8	2.5	V	V_{DS} = V_{GS} , I_D = 250 μ A	
Forward Transfer Admittance *1	y _{fs}	26	52		S	V_{DS} = 5 V, I_{D} = 38 A	
Drain to Source On-state Resistance *1	R _{DS(on)1}		4.7	5.7	mΩ	V_{GS} = 10 V, I_{D} = 38 A	
	R _{DS(on)2}		6.3	12.6	mΩ	V_{GS} = 4.5 V, I _D = 19 A	
Input Capacitance *2	Ciss		1630	2450	pF	V _{DS} = 25 V	
Output Capacitance *2	Coss	_	220	330	pF	$V_{GS} = 0 V$	
Reverse Transfer Capacitance *2	Crss		100	180	pF	f = 1 MHz	
Turn-on Delay Time *2	t _{d(on)}		12	26	ns	V _{DD} = 20 V, I _D = 38 A	
Rise Time *2	tr		5	13	ns	V _{GS} = 10 V	
Turn-off Delay Time *2	t _{d(off)}		40	80	ns	R _G = 0 Ω	
Fall Time *2	t _f	_	5	13	ns		
Total Gate Charge *2	Q _G	_	27	41	nC	V _{DD} = 32 V	
Gate to Source Charge	Q _{GS}	_	8	_	nC	V _{GS} = 10 V	
Gate to Drain Charge	Q _{GD}		4	_	nC	I _D = 75 A	
Body Diode Forward Voltage *1	V _{F(S-D)}		0.9	1.5	V	I _F = 75 A, V _{GS} = 0 V	
Reverse Recovery Time	trr		32	_	ns	I _F = 75 A, V _{GS} = 0 V	
Reverse Recovery Charge	Qrr		35		nC	di/dt = 100 A/µs	

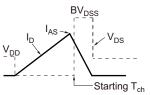
Note: *1 Pulsed test

Note: *2 Not subject of production test. Verified by design/characterization.

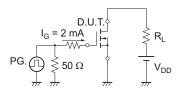
TEST CIRCUIT 1 AVALANCHE CAPABILITY

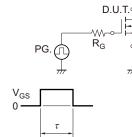
TEST CIRCUIT 2 SWITCHING TIME



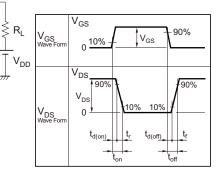


TEST CIRCUIT 3 GATE CHARGE



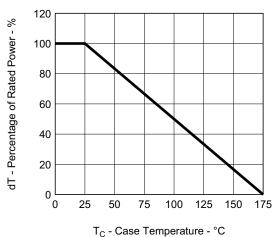


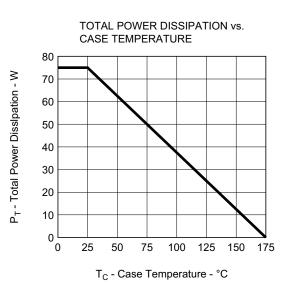




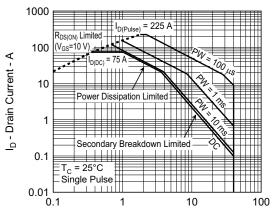
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

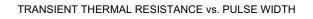


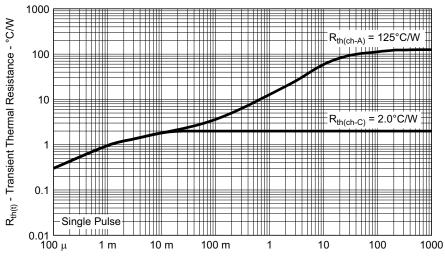


FORWARD BIAS SAFE OPERATING AREA

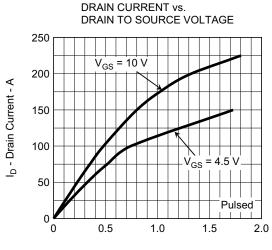




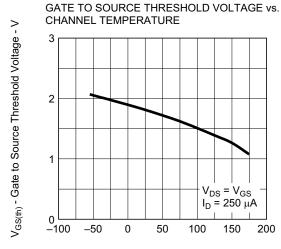




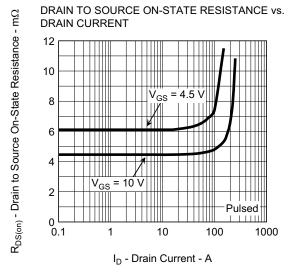




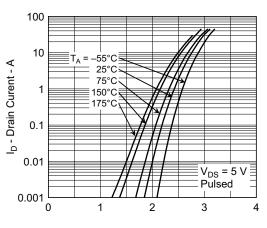
V_{DS} - Drain to Source Voltage - V



T_{ch} - Channel Temperature - °C

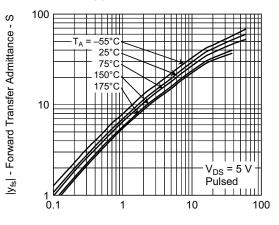


FORWARD TRANSFER CHARACTERISTICS

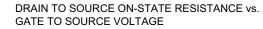


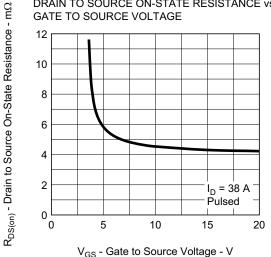


FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



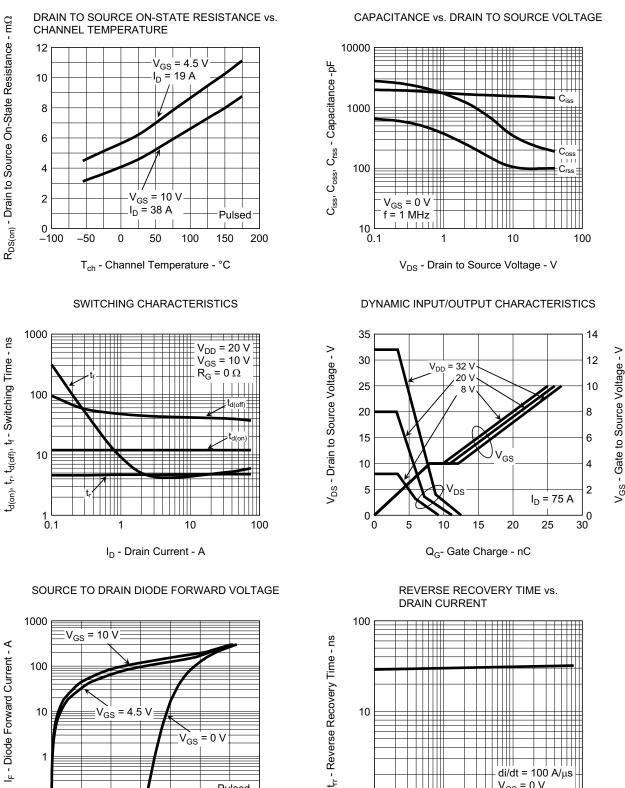
I_D - Drain Current - A

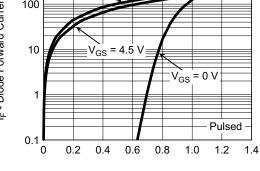




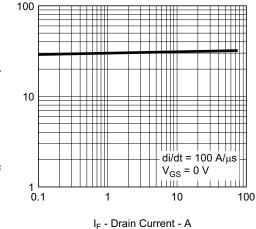


NP75N04VDK







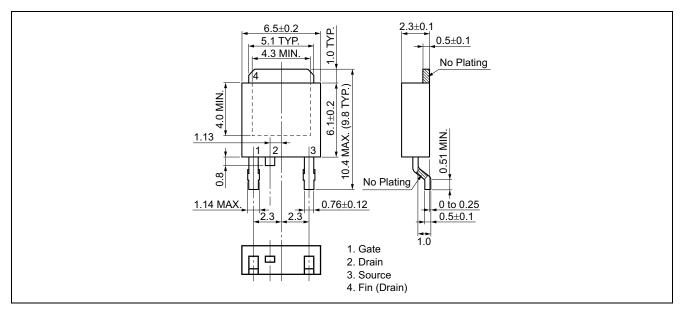


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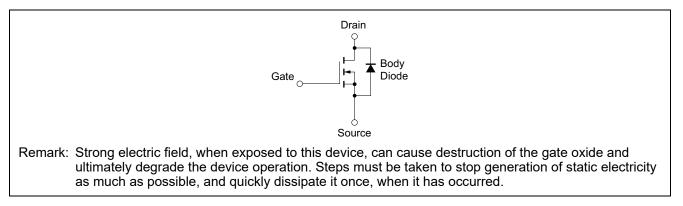


Package Drawing (Unit: mm)

TO-252 (MP-3ZP) (Mass: 0.3g TYP.)



Equivalent Circuit





Revision History

NP75N04VDK Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Feb 21, 2013		First Edition Issued	
2.00	May 24 ,2018	1	Note 3 was added	
		2	Note 2 was added	

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